

MC14543B

BCD-to-Seven Segment Latch/Decoder/Driver for Liquid Crystals

The MC14543B BCD-to-seven segment latch/decoder/driver is designed for use with liquid crystal readouts, and is constructed with complementary MOS (CMOS) enhancement mode devices. The circuit provides the functions of a 4-bit storage latch and an 8421 BCD-to-seven segment decoder and driver. The device has the capability to invert the logic levels of the output combination. The phase (Ph), blanking (BI), and latch disable (LD) inputs are used to reverse the truth table phase, blank the display, and store a BCD code, respectively. For liquid crystal (LC) readouts, a square wave is applied to the Ph input of the circuit and the electrically common backplane of the display. The outputs of the circuit are connected directly to the segments of the LC readout. For other types of readouts, such as light-emitting diode (LED), incandescent, gas discharge, and fluorescent readouts, connection diagrams are given on this data sheet.

Applications include instrument (e.g., counter, DVM etc.) display driver, computer/calculator display driver, cockpit display driver, and various clock, watch, and timer uses.

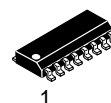
Features

- Latch Storage of Code
- Blanking Input
- Readout Blanking on All Illegal Input Combinations
- Direct LED (Common Anode or Cathode) Driving Capability
- Supply Voltage Range = 3.0 V to 18 V
- Capable of Driving 2 Low-power TTL Loads, 1 Low-power Schottky TTL Load or 2 HTL Loads Over the Rated Temperature Range
- Pin-for-Pin Replacement for CD4056A (with Pin 7 Tied to V_{SS}).
- Chip Complexity: 207 FETs or 52 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.
- This Device is Pb-Free and is RoHS Compliant



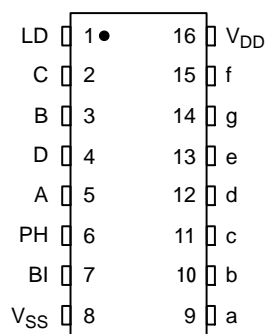
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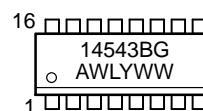


SOIC-16
D SUFFIX
CASE 751B

PIN ASSIGNMENT



MARKING DIAGRAM



A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

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MAXIMUM RATINGS (Voltages Referenced to V_{SS})

| Parameter | Symbol | Value | Unit |
|---|----------------------------|------------------------|--------------------|
| DC Supply Voltage Range | V_{DD} | -0.5 to +18.0 | V |
| Input Voltage Range, All Inputs | V_{in} | -0.5 to $V_{DD} + 0.5$ | V |
| DC Input Current per Pin | I_{in} | ± 10 | mA |
| Power Dissipation per Package (Note 1) | P_D | 500 | mW |
| Operating Temperature Range | T_A | -55 to +125 | $^{\circ}\text{C}$ |
| Storage Temperature Range | T_{stg} | -65 to +150 | $^{\circ}\text{C}$ |
| Maximum Continuous Output Drive Current (Source or Sink) | I_{OHmax} I_{OLmax} | 10 (per Output) | mA |
| Maximum Continuous Output Power (Source or Sink) (Note 2) | P_{OHmax} P_{OLmax} | 70 (per Output) | mW |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Package: -7.0 mW/ $^{\circ}\text{C}$ From 65 $^{\circ}\text{C}$ To 125 $^{\circ}\text{C}$

2. $P_{OHmax} = I_{OH} (V_{OH} - V_{DD})$ and $P_{OLmax} = I_{OL} (V_{OL} - V_{SS})$

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

TRUTH TABLE

| Inputs | | | | | | | Outputs | | | | | | | |
|--------|----|-----|---|---|---|---|--------------------------------------|---|---|---|---|---|---|------------------|
| LD | BI | Ph* | D | C | B | A | a | b | c | d | e | f | g | Display |
| X | 1 | 0 | X | X | X | X | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 |
| 1 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 2 |
| 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 3 |
| 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 4 |
| 1 | 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 5 |
| 1 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 6 |
| 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 7 |
| 1 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 8 |
| 1 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 9 |
| 1 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 1 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Blank |
| 0 | 0 | 0 | X | X | X | X | ** | | | | | | | ** |
| † | † | † | † | | | | Inverse of Output Combinations Above | | | | | | | Display as above |

X = Don't care

† = Above Combinations

* = For liquid crystal readouts, apply a square wave to Ph

For common cathode LED readouts, select Ph = 0

For common anode LED readouts, select Ph = 1

** = Depends upon the BCD code previously applied when LD = 1

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ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

| Characteristic | Symbol | V _{DD} Vdc | - 55° C | | 25° C | | | 125° C | | Unit | |
|--|--|------------------------|---|-------|-------|-----------------|-------|--------|-------|------|------|
| | | | Min | Max | Min | Typ (Note 3) | Max | Min | Max | | |
| Output Voltage "0" Level V _{in} = V _{DD} or 0 | V _{OL} | 5.0 | – | 0.05 | – | 0 | 0.05 | – | 0.05 | Vdc | |
| | | 10 | – | 0.05 | – | 0 | 0.05 | – | 0.05 | | |
| 15 | | – | 0.05 | – | 0 | 0.05 | – | 0.05 | | | |
| "1" Level V _{in} = 0 or V _{DD} | V _{OH} | 5.0 | 4.95 | – | 4.95 | 5.0 | – | 4.95 | – | Vdc | |
| | | 10 | 9.95 | – | 9.95 | 10 | – | 9.95 | – | | |
| | | 15 | 14.95 | – | 14.95 | 15 | – | 14.95 | – | | |
| Input Voltage "0" Level (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc) | V _{IL} | 5.0 | – | 1.5 | – | 2.25 | 1.5 | – | 1.5 | Vdc | |
| | | 10 | – | 3.0 | – | 4.50 | 3.0 | – | 3.0 | | |
| 15 | | – | 4.0 | – | 6.75 | 4.0 | – | 4.0 | | | |
| "1" Level (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc) | V _{IH} | 5.0 | 3.5 | – | 3.5 | 2.75 | – | 3.5 | – | Vdc | |
| | | 10 | 7.0 | – | 7.0 | 5.50 | – | 7.0 | – | | |
| | | 15 | 11 | – | 11 | 8.25 | – | 11 | – | | |
| Output Drive Current (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 0.5 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc) | Source Sink | I _{OH} | 5.0 | –3.0 | – | –2.4 | –4.2 | – | –1.7 | – | mAdc |
| | | | 5.0 | –0.64 | – | –0.51 | –0.88 | – | –0.36 | – | |
| 10 | | | – | – | – | –10.1 | – | – | – | | |
| 10 | | | –1.6 | – | –1.3 | –2.25 | – | –0.9 | – | | |
| 15 | | | –4.2 | – | –3.4 | –8.8 | – | –2.4 | – | | |
| (V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 9.5 Vdc) (V _{OL} = 1.5 Vdc) | I _{OL} | 5.0 | 0.64 | – | 0.51 | 0.88 | – | 0.36 | – | mAdc | |
| | | 10 | 1.6 | – | 1.3 | 2.25 | – | 0.9 | – | | |
| | | 10 | – | – | – | 10.1 | – | – | – | | |
| | | 15 | 4.2 | – | 3.4 | 8.8 | – | 2.4 | – | | |
| Input Current | I _{in} | 15 | – | ±0.1 | – | ±0.00001 | ±0.1 | – | ±1.0 | μAdc | |
| Input Capacitance | C _{in} | – | – | – | – | 5.0 | 7.5 | – | – | pF | |
| Quiescent Current (Per Package) V _{in} = 0 or V _{DD} , I _{out} = 0 μA | I _{DD} | 5.0 | – | 5.0 | – | 0.005 | 5.0 | – | 150 | μAdc | |
| 10 | – | 10 | – | 0.010 | 10 | – | 300 | | | | |
| 15 | – | 20 | – | 0.015 | 20 | – | 600 | | | | |
| Total Supply Current (Note 4, 5) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching) | I _T | 5.0 | I _T = (1.6 μA/kHz) f + I _{DD} I _T = (3.1 μA/kHz) f + I _{DD} I _T = (4.7 μA/kHz) f + I _{DD} | | | | | | | μAdc | |
| 10 | | | | | | | | | | | |
| 15 | | | | | | | | | | | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Noise immunity specified for worst-case input combination.

$$\begin{aligned} \text{Noise Margin for both "1" and "0" level} &= 1.0 \text{ V min @ } V_{DD} = 5.0 \text{ V} \\ &= 2.0 \text{ V min @ } V_{DD} = 10 \text{ V} \\ &= 2.5 \text{ V min @ } V_{DD} = 15 \text{ V} \end{aligned}$$

4. To calculate total supply current at loads other than 50 pF: $I_T(C_L) = I_T(50 \text{ pF}) + 3.5 \times 10^{-3} (C_L - 50) V_{DD} f$ where: I_T is in μA (per package), C_L in pF, V_{DD} in V, and f in kHz is input frequency.

5. The formulas given are for the typical characteristics only at 25°C.

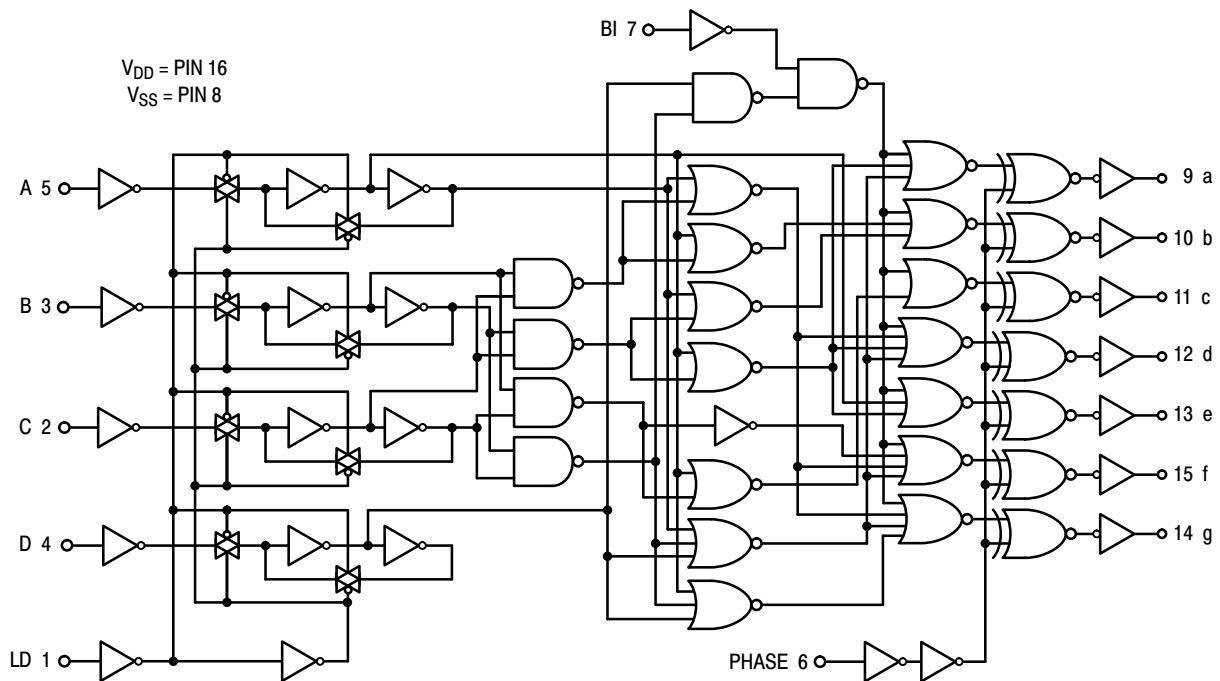
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SWITCHING CHARACTERISTICS (Note 6) ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$)

| Characteristic | Symbol | V _{DD} | Min | Typ | Max | Unit |
|--|-----------|-----------------|-------------------|-------------------|--------------------|------|
| Output Rise Time $t_{TLH} = (3.0 \text{ ns/pF}) C_L + 30 \text{ ns}$ $t_{TLH} = (1.5 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{TLH} = (1.1 \text{ ns/pF}) C_L + 10 \text{ ns}$ | t_{TLH} | 5.0 10 15 | – – – | 100 50 40 | 200 100 80 | ns |
| Output Fall Time $t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{THL} = (0.55 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ | t_{THL} | 5.0 10 15 | – – – | 100 50 40 | 200 100 80 | ns |
| Turn-Off Delay Time $t_{PLH} = (1.7 \text{ ns/pF}) C_L + 520 \text{ ns}$ $t_{PLH} = (0.66 \text{ ns/pF}) C_L + 217 \text{ ns}$ $t_{PLH} = (0.5 \text{ ns/pF}) C_L + 160 \text{ ns}$ | t_{PLH} | 5.0 10 15 | – – – | 605 250 185 | 1210 500 370 | ns |
| Turn-On Delay Time $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 420 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 172 \text{ ns}$ $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 130 \text{ ns}$ | t_{PHL} | 5.0 10 15 | – – – | 505 205 155 | 1650 660 495 | ns |
| Setup Time | t_{su} | 5.0 10 15 | 350 450 500 | | – – – | ns |
| Hold Time | t_h | 5.0 10 15 | 40 30 20 | | – – – | ns |
| Latch Disable Pulse Width (Strobing Data) | t_{WH} | 5.0 10 15 | 250 100 80 | 125 50 40 | – – – | ns |

6. The formulas given are for the typical characteristics only.

LOGIC DIAGRAM



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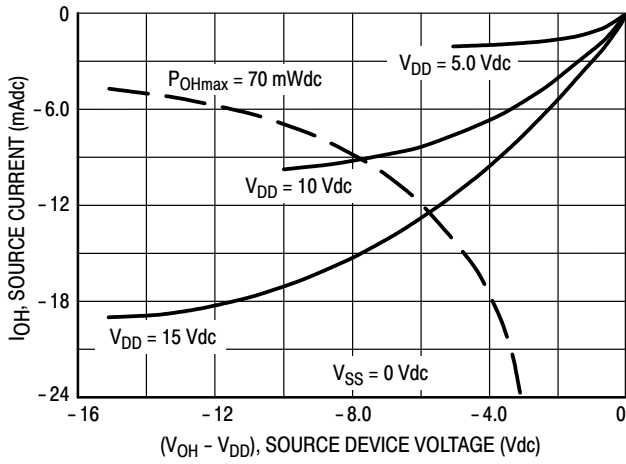


Figure 1. Typical Output Source Characteristics

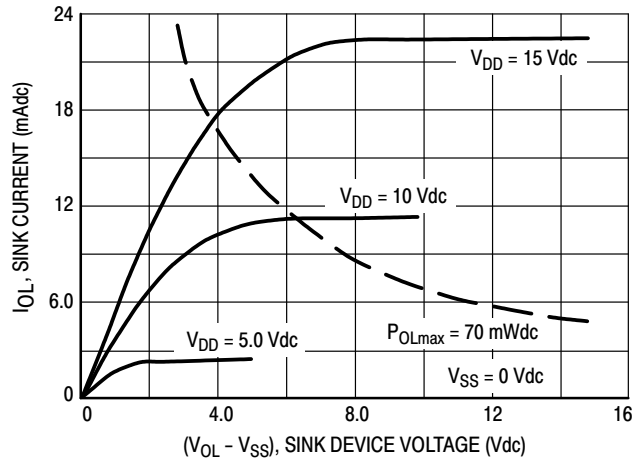


Figure 2. Typical Output Sink Characteristics

Inputs BI and Ph low, and Inputs D and LD high.
f in respect to a system clock.
All outputs connected to respective C_L loads.

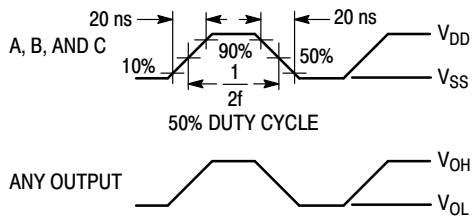
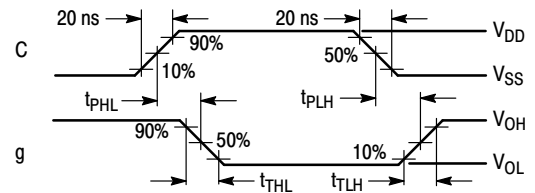
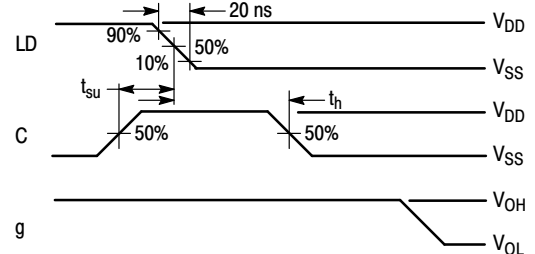


Figure 3. Dynamic Power Dissipation Signal Waveforms

(a) Inputs D, Ph, and BI low, and Inputs A, B, and LD high.



(b) Inputs D, Ph, and BI low, and Inputs A and B high.



(c) Data DCBA strobed into latches

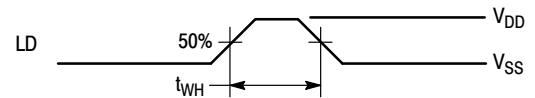
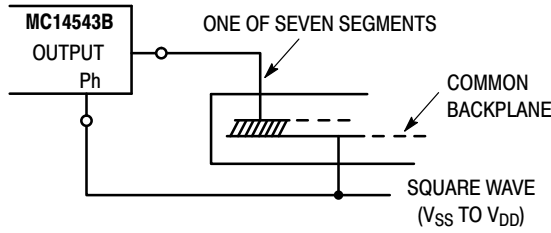


Figure 4. Dynamic Signal Waveforms

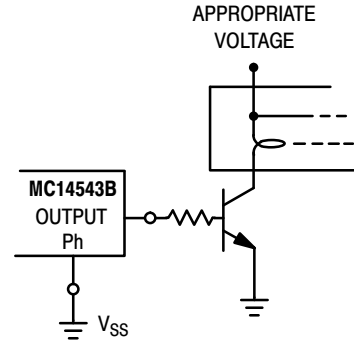
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CONNECTIONS TO VARIOUS DISPLAY READOUTS

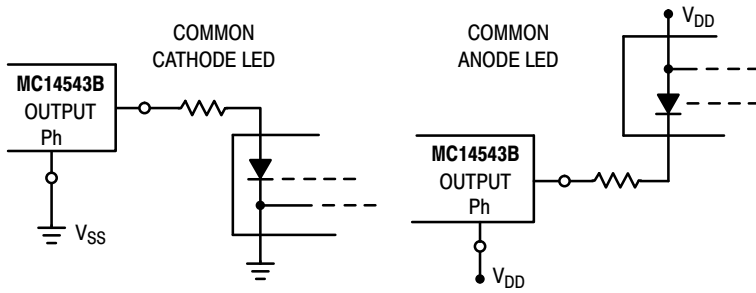
LIQUID CRYSTAL (LC) READOUT



INCANDESCENT READOUT

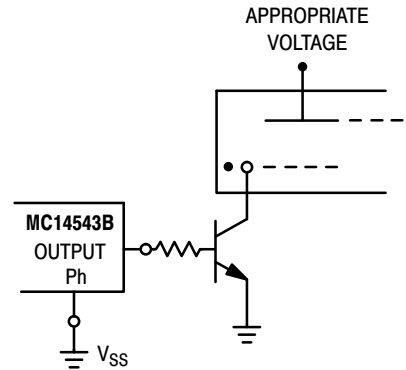


LIGHT EMITTING DIODE (LED) READOUT

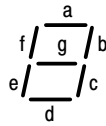


NOTE: Bipolar transistors may be added for gain (for $V_{DD} \leq 10\text{ V}$ or $I_{out} \geq 10\text{ mA}$).

GAS DISCHARGE READOUT

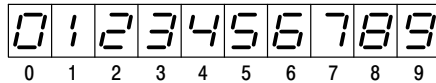


CONNECTIONS TO SEGMENTS



V_{DD} = PIN 16
 V_{SS} = PIN 8

DISPLAY



MC14543B

ORDERING INFORMATION

| Device | Package | Shipping† |
|----------------|----------------------|--------------------|
| MC14543BDG | SOIC-16 (Pb-Free) | 48 Units / Rail |
| MC14543BDR2G | SOIC-16 (Pb-Free) | 2500 / Tape & Reel |
| NLV14543BDR2G* | SOIC-16 (Pb-Free) | 2500 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®



SCALE 1:1

SOIC-16 CASE 751B-05 ISSUE K

DATE 29 DEC 2006



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 9.80 | 10.00 | 0.386 | 0.393 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 BSC | | 0.050 BSC | |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| M | 0° | 7° | 0° | 7° |
| P | 5.80 | 6.20 | 0.229 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |

- | | | | |
|--|--|--|--|
| <p>STYLE 1:</p> <p>PIN 1. COLLECTOR</p> <p>2. BASE</p> <p>3. EMITTER</p> <p>4. NO CONNECTION</p> <p>5. EMITTER</p> <p>6. BASE</p> <p>7. COLLECTOR</p> <p>8. COLLECTOR</p> <p>9. BASE</p> <p>10. EMITTER</p> <p>11. NO CONNECTION</p> <p>12. EMITTER</p> <p>13. BASE</p> <p>14. COLLECTOR</p> <p>15. EMITTER</p> <p>16. COLLECTOR</p> | <p>STYLE 2:</p> <p>PIN 1. CATHODE</p> <p>2. ANODE</p> <p>3. NO CONNECTION</p> <p>4. CATHODE</p> <p>5. CATHODE</p> <p>6. NO CONNECTION</p> <p>7. ANODE</p> <p>8. CATHODE</p> <p>9. CATHODE</p> <p>10. ANODE</p> <p>11. NO CONNECTION</p> <p>12. CATHODE</p> <p>13. CATHODE</p> <p>14. NO CONNECTION</p> <p>15. ANODE</p> <p>16. CATHODE</p> | <p>STYLE 3:</p> <p>PIN 1. COLLECTOR, DYE #1</p> <p>2. BASE, #1</p> <p>3. EMITTER, #1</p> <p>4. COLLECTOR, #1</p> <p>5. COLLECTOR, #2</p> <p>6. BASE, #2</p> <p>7. EMITTER, #2</p> <p>8. COLLECTOR, #2</p> <p>9. COLLECTOR, #3</p> <p>10. BASE, #3</p> <p>11. EMITTER, #3</p> <p>12. COLLECTOR, #3</p> <p>13. COLLECTOR, #4</p> <p>14. BASE, #4</p> <p>15. EMITTER, #4</p> <p>16. COLLECTOR, #4</p> | <p>STYLE 4:</p> <p>PIN 1. COLLECTOR, DYE #1</p> <p>2. COLLECTOR, #1</p> <p>3. COLLECTOR, #2</p> <p>4. COLLECTOR, #2</p> <p>5. COLLECTOR, #3</p> <p>6. COLLECTOR, #3</p> <p>7. COLLECTOR, #4</p> <p>8. COLLECTOR, #4</p> <p>9. BASE, #4</p> <p>10. EMITTER, #4</p> <p>11. BASE, #3</p> <p>12. EMITTER, #3</p> <p>13. BASE, #2</p> <p>14. EMITTER, #2</p> <p>15. BASE, #1</p> <p>16. EMITTER, #1</p> |
| <p>STYLE 5:</p> <p>PIN 1. DRAIN, DYE #1</p> <p>2. DRAIN, #1</p> <p>3. DRAIN, #2</p> <p>4. DRAIN, #2</p> <p>5. DRAIN, #3</p> <p>6. DRAIN, #3</p> <p>7. DRAIN, #4</p> <p>8. DRAIN, #4</p> <p>9. GATE, #4</p> <p>10. SOURCE, #4</p> <p>11. GATE, #3</p> <p>12. SOURCE, #3</p> <p>13. GATE, #2</p> <p>14. SOURCE, #2</p> <p>15. GATE, #1</p> <p>16. SOURCE, #1</p> | <p>STYLE 6:</p> <p>PIN 1. CATHODE</p> <p>2. CATHODE</p> <p>3. CATHODE</p> <p>4. CATHODE</p> <p>5. CATHODE</p> <p>6. CATHODE</p> <p>7. CATHODE</p> <p>8. CATHODE</p> <p>9. ANODE</p> <p>10. ANODE</p> <p>11. ANODE</p> <p>12. ANODE</p> <p>13. ANODE</p> <p>14. ANODE</p> <p>15. ANODE</p> <p>16. ANODE</p> | <p>STYLE 7:</p> <p>PIN 1. SOURCE N-CH</p> <p>2. COMMON DRAIN (OUTPUT)</p> <p>3. COMMON DRAIN (OUTPUT)</p> <p>4. GATE P-CH</p> <p>5. COMMON DRAIN (OUTPUT)</p> <p>6. COMMON DRAIN (OUTPUT)</p> <p>7. COMMON DRAIN (OUTPUT)</p> <p>8. SOURCE P-CH</p> <p>9. SOURCE P-CH</p> <p>10. COMMON DRAIN (OUTPUT)</p> <p>11. COMMON DRAIN (OUTPUT)</p> <p>12. COMMON DRAIN (OUTPUT)</p> <p>13. GATE N-CH</p> <p>14. COMMON DRAIN (OUTPUT)</p> <p>15. COMMON DRAIN (OUTPUT)</p> <p>16. SOURCE N-CH</p> | |

SOLDERING FOOTPRINT



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